TOSHIBA TLP250

TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

# **TLP250**

Transistor Inverter
Inverter For Air Conditioner
IGBT Gate Drive
Power MOS FET Gate Drive

The TOSHIBA TLP250 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP250 is suitable for gate driving circuit of IGBT or power MOS FET.

- Input threshold current: IF=5mA(max.)
- Supply current (ICC): 11mA(max.)
- Supply voltage (VCC): 10-35V
- Output current (IO): ±1.5A (max.)
- Switching time (tpLH/tpHL): 0.5µs(max.)
- Isolation voltage: 2500V<sub>rms</sub>(min.)
- UL recognized: UL1577, file No.E67349
- Option(D4)

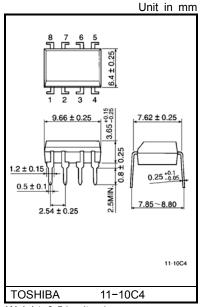
VDE Approved : DIN EN60747-5-2

 $\label{eq:maximum operating Insulation Voltage} \begin{tabular}{ll} A 400V_{PK} \\ Highest Permissible Over Voltage \\ \end{tabular} \begin{tabular}{ll} 4000V_{PK} \\ \end{tabular}$ 

(Note): When a EN60747-5-2 approved type is needed, Please designate "Option(D4)"

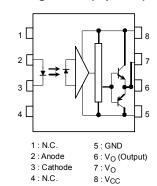
### **Truth Table**

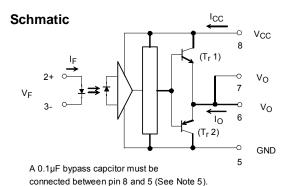
		Tr1	Tr2
Input LED	On	On	Off
	Off	Off	On



Weight: 0.54 g (typ.)

### Pin Configuration (top view)





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### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit		
	Forward current	lF	20	mA		
	Forward current derating (Ta ≥ 70°C)	ΔI <sub>F</sub> / ΔTa	-0.36	mA / °C		
LED	Peak transient forward curent	I <sub>FPT</sub>	1	Α		
	Reverse voltage		$V_{R}$	5	V	
	Junction temperature		Tj	125	°C	
	"H"peak output current (P <sub>W</sub> ≤ 2.5µs,f ≤ 15kHz)	(Note 2)	I <sub>OPH</sub>	-1.5	Α	
	"L"peak output current (P <sub>W</sub> ≤ 2.5µs,f ≤ 15kHz)	(Note 2)	I <sub>OPL</sub>	+1.5	Α	
	Output voltage	(Ta ≤ 70°C)	Vo	35	V	
tor	Output voitage	(Ta = 85°C)	V	24	V	
Detector	Supply voltage	(Ta ≤ 70°C)	V <sub>CC</sub>	35	V	
اد ا	Cuppiy voltage	(Ta = 85°C)	VCC	24	V	
	Output voltage derating (Ta ≥ 70°C)	$\Delta V_O$ / $\Delta Ta$	-0.73	V/°C		
	Supply voltage derating (Ta ≥ 70°C)		$\Delta V_{CC}$ / $\Delta Ta$	-0.73	V/°C	
	Junction temperature	Tj	125	°C		
Opera	ating frequency	f	25	kHz		
Opera	ating temperature range	T <sub>opr</sub>	-20~85	°C		
Storage temperature range			T <sub>stg</sub>	-55~125	°C	
Lead	Lead soldering temperature (10 s)			260	°C	
Isolat	ion voltage (AC, 1 min., R.H.≤ 60%)	$BV_S$	2500	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width  $P_W \le 1\mu s$ , 300pps
- Note 2: Exporenential waveform
- Note 3: Exporenential wavefom,  $I_{OPH} \le -1.0A(\le 2.5 \mu s)$ ,  $I_{OPL} \le +1.0A(\le 2.5 \mu s)$
- Note 4: Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.
- Note 5: A ceramic capacitor(0.1µF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching proparty. The total lead length between capacitor and coupler should not exceed 1cm.

## **Recommended Operating Conditions**

Characteristic		Symbol	Min	Тур.	Max		Unit
Input current, on	(Note6)	I <sub>F(ON)</sub>	7	8	10		mA
Input voltage, off		V <sub>F(OFF)</sub>	0	1	0.8		V
Supply voltage		V <sub>CC</sub>	15	_	30	20	V
Peak output current		IOPH/IOPL		1	±0.5		Α
Operating temperature		T <sub>opr</sub>	-20	25	70	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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Note 6: Input signal rise time(fall time)<0.5 $\mu$ s.

# Electrical Characteristics ( $Ta = -20 \sim 70$ °C, unless otherwise specified)

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min	Typ.*	Max	Unit	
Input forward voltage		V <sub>F</sub>	_	I <sub>F</sub> = 10 mA , Ta = 25°C	_	1.6	1.8	V	
Temperature coeffici forward voltage	ent of	ΔV <sub>F</sub> / ΔTa	_	I <sub>F</sub> = 10 mA	_	-2.0	_	mV / °C	
Input reverse current	1	I <sub>R</sub>	_	V <sub>R</sub> = 5V, Ta = 25°C	_	_	10	μА	
Input capacitance		C <sub>T</sub>	_	V = 0 , f = 1MHz , Ta = 25°C	_	45	250	pF	
Output current	"H" level	I <sub>OPH</sub>	1	$V_{CC} = 30V$ $I_F = 10 \text{ mA}$ $V_{8-6} = 4V$	-0.5	-1.5	_	^	
	"L" level	I <sub>OPL</sub>	2	(*1) $ I_{F} = 0 \\ V_{6-5} = 2.5V $	0.5	2	_	A	
Output voltage	"H" level	V <sub>OH</sub>	3	$V_{CC1}$ = +15V, $V_{EE1}$ = -15V $R_L$ = 200 $\Omega$ , $I_F$ = 5mA	11	12.8	_	- V	
Output voltage	"L" level	V <sub>OL</sub>	4	$V_{CC1}$ = +15V, $V_{EE1}$ = -15V $R_L$ = 200 $\Omega$ , $V_F$ = 0.8V	_	-14.2	-12.5		
	"H" level	Іссн	_	V <sub>CC</sub> = 30V, I <sub>F</sub> = 10mA Ta = 25°C	_	7	_		
Supply current				V <sub>CC</sub> = 30V, I <sub>F</sub> = 10mA — -		_	11	mA	
Supply current	"L" level	ICCL	_	V <sub>CC</sub> = 30V, I <sub>F</sub> = 0mA Ta = 25°C	_	7.5	_	IIIA	
				V <sub>CC</sub> = 30V, I <sub>F</sub> = 0mA	_	_	11		
Threshold input current	"Output L→H"	I <sub>FLH</sub>	_	$V_{CC1}$ = +15V, $V_{EE1}$ = -15V $R_L$ = 200 $\Omega$ , $V_O$ > 0V	_	1.2	5	mA	
Threshold input voltage	"Output H→L"	$V_{FHL}$	_	$V_{CC1}$ = +15V, $V_{EE1}$ = -15V $R_L$ = 200 $\Omega$ , $V_O$ < 0V	0.8	_	_	V	
Supply voltage		V <sub>CC</sub>	_		10	_	35	V	
Capacitance (input-output)		CS	_	V <sub>S</sub> = 0 , f = 1MHz Ta = 25°C	_	1.0	2.0	pF	
Resistance(input-output)		R <sub>S</sub>	_	V <sub>S</sub> = 500V , Ta = 25°C R.H.≤ 60%	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω	

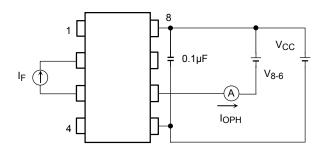
<sup>\*</sup> All typical values are at Ta =  $25^{\circ}$ C (\*1): Duration of I<sub>O</sub> time  $\leq 50 \mu s$ 

# Switching Characteristics (Ta = $-20\sim70^{\circ}$ C , unless otherwise specified)

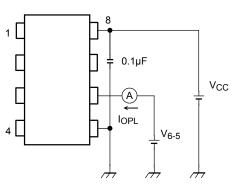
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min	Typ.*	Max	Unit
Propagation delay time	L→H	t <sub>pLH</sub>	5	I <sub>F</sub> = 8mA V <sub>CC1</sub> = +15V, V <sub>FF1</sub> = -15V	_	0.15	0.5	
	H→L	t <sub>pHL</sub>			_	0.15	0.5	
Output rise time		t <sub>r</sub>	5	$R_L = 200\Omega$	_	_	_	μs
Output fall time		t <sub>f</sub>			_	_	_	
Common mode transient immunity at high level C <sub>MH</sub> output		6	V <sub>CM</sub> = 600V, I <sub>F</sub> = 8mA V <sub>CC</sub> = 30V, Ta = 25°C	-5000	_	_	V / µs	
Common mode transier immunity at low level output	nt	C <sub>ML</sub>	0	V <sub>CM</sub> = 600V, I <sub>F</sub> = 0mA V <sub>CC</sub> = 30V, Ta = 25°C	5000	_	_	V / µs

All typical values are at Ta = 25°C

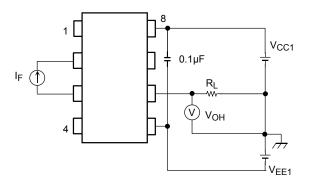
Test Circuit 1: IOPH



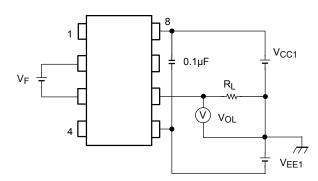
Test Circuit 2 : I<sub>OPL</sub>



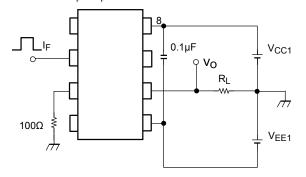
Test Circuit 3: VOH

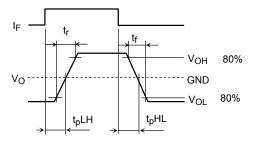


Test Circuit 4 : V<sub>OL</sub>

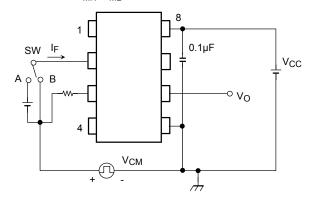


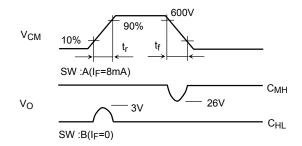
Test Circuit 5:  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_{r}$   $t_{f}$ 





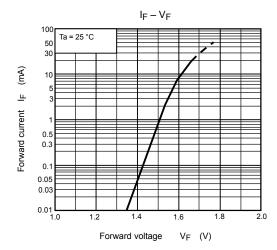
Test Circuit 6: C<sub>MH</sub>, C<sub>ML</sub>

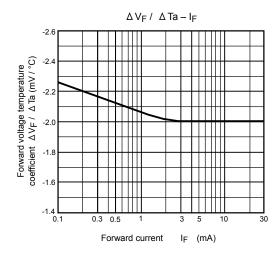


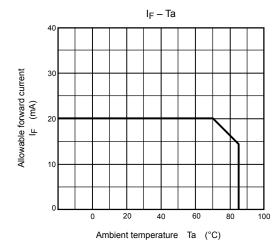


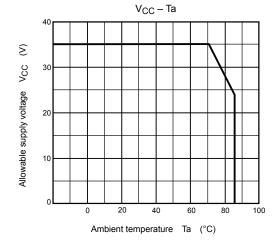
$$\begin{split} C_{ML} &= \frac{480 \text{ (V)}}{t_{\Gamma \text{ (}\mu\text{s)}}} \\ C_{MH} &= \frac{480 \text{ (V)}}{t_{f \text{ (}\mu\text{s)}}} \end{split}$$

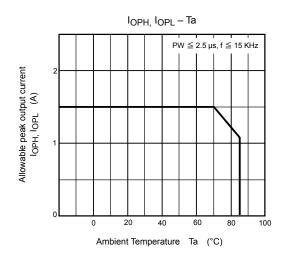
 $C_{ML}(C_{MH})$  is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.











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